MOSFET - Power, Single N-Channel, SO8-FL 30 V, 0.65 mΩ, 409 A

NTMFS0D7N03CG

Features

- Wide SOA to Improve Inrush Current Management
- Advanced Package (5x6mm) with Excellent Thermal Conduction
- Ultra Low R_{DS(on)} to Improve System Efficiency
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Hot Swap Application
- Power Load Switch
- Battery Management and Protection

MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	30	V
Gate-to-Source Voltage			V _{GS}	±20	V
Continuous Drain		$T_C = 25^{\circ}C$	۱ _D	409	А
Current R _{θJC} (Note 2)	Steady	T _C =100°C	1	289	
Power Dissipation $R_{\theta JC}$ (Note 2)	State	T _C = 25°C	PD	187	W
Continuous Drain		$T_A = 25^{\circ}C$	Ι _D	59	А
Current R _{θJA} (Notes 1, 2)	Steady	T _A = 100°C	1	42	
Power Dissipation $R_{\theta JA}$ (Notes 1, 2)	State	T _A = 25°C	P _D	4.0	W
Pulsed Drain Current	T _A = 25°	C, t _p = 10 μs	I _{DM}	900	А
Source Current (Body Diode)			I _S	155	А
Single Pulse Drain-to-Source Avalanche Energy ($I_L = 40.8 A_{pk}$)			E _{AS}	1080	mJ
Operating Junction and Storage Temperature Range			T _J , T _{STG}	–55 to +175	°C
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface-mounted on FR4 board using 1 in² pad, 2 oz Cu pad.

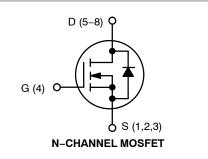
The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

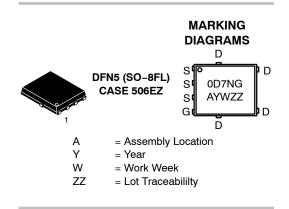


ON Semiconductor®

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V _{(BR)DSS}	R _{DS(ON)} MAX	I _D MAX
30 V	$0.65~\mathrm{m}\Omega @~10~\mathrm{V}$	409 A





ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

THERMAL RESISTANCE MAXIMUM RATINGS

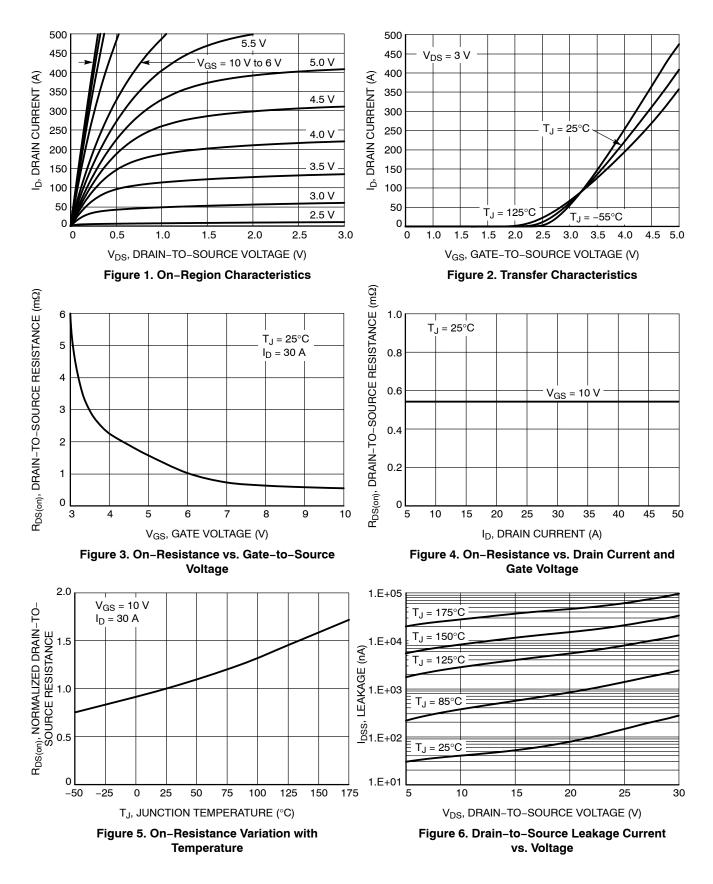
Parameter	Symbol	Value	Unit	
Junction-to-Case - Steady State (Note 1)	$R_{\theta JC}$	0.8	°C/W	
Junction-to-Ambient - Steady State (Note 1)	R_{\thetaJA}	38		
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	134	°C/W	

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

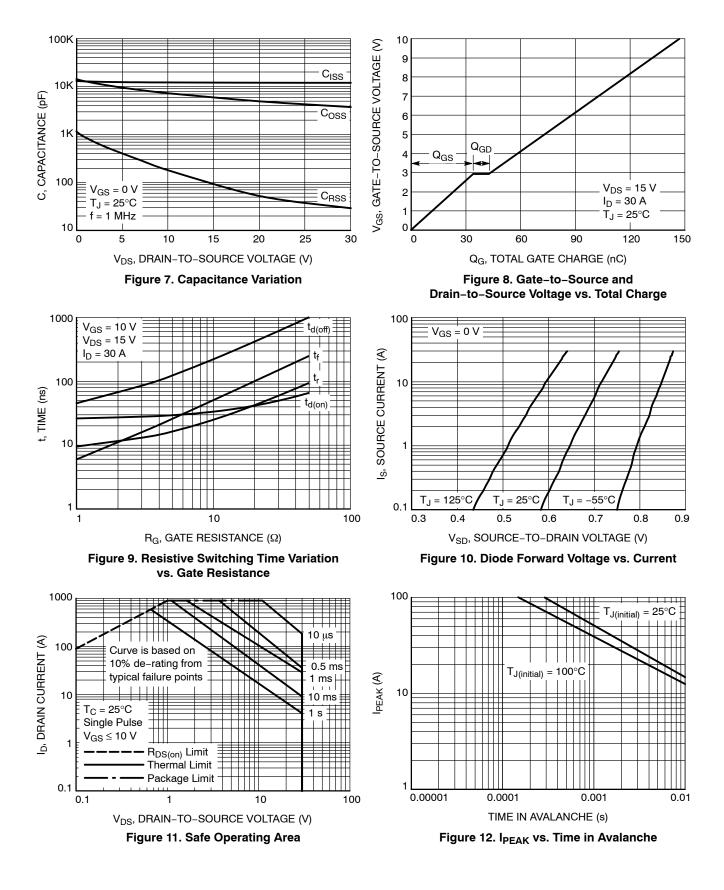
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I_D = 250 μ A		30			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} / T _J	$I_D = 250 \ \mu A. ref to 25^{\circ}C$			11		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	$V_{GS} = 0 V, T_J = 25^{\circ}C$				1.0	
		V _{DS} = 30 V	T _J = 125°C			100	μΑ
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{G}$	_{iS} = 20 V			100	nA
ON CHARACTERISTICS (Note 3)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$, $I_D = 280 \ \mu A$		1.3		2.2	V
Threshold Temperature Coefficient	V _{GS(TH)} /T _J	I _D = 280 μA. ref to 25°C			-5.1		mV/°0
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V, I _D = 30 A			0.55	0.65	mΩ
Forward Transconductance	9 _{FS}	V _{DS} = 3 V, I _D = 30 A			100		S
Gate Resistance	R _G	T _A = 25°C			0.4	3.0	Ω
CHARGES AND CAPACITANCES							
Input Capacitance	C _{ISS}	V _{GS} = 0 V, V _{DS} = 15 V, f = 1 MHz		8600	12300	16000	pF
Output Capacitance	C _{OSS}			4000	5800	7500	
Reverse Transfer Capacitance	C _{RSS}			50	88	360	
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 10 V, V _{DS} = 15 V; I _D = 30 A		103	147	191	nC
Threshold Gate Charge	Q _{G(TH)}			13	19	25	
Gate-to-Source Charge	Q _{GS}			24	34	44	
Gate-to-Drain Charge	Q _{GD}			5.2	8.6	20.5	
SWITCHING CHARACTERISTICS (Note 4)						
Turn-On Delay Time	t _{d(ON)}				28		
Rise Time	tr	V_{GS} = 10 V, V_{DS} = 15 V, I_{D} = 30 A, R_{G} = 3.0 Ω			13		- ns
Turn-Off Delay Time	t _{d(OFF)}				85		
Fall Time	t _f				16		
DRAIN-SOURCE DIODE CHARACTERIS	TICS						
Forward Diode Voltage	V _{SD}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$		0.78	1.2	
		$I_{\rm S} = 30 \rm A$	T _J = 125°C		0.62		V
Reverse Recovery Time	t _{RR}	$\label{eq:VGS} \begin{array}{l} V_{GS} = 0 \text{ V, } \text{dIS/dt} = 100 \text{ A/}\mu\text{s}, \\ V_{DS} = 15 \text{ V, } \text{I}_S = 30 \text{ A} \end{array}$			98		ns
Reverse Recovery Charge	Q _{RR}				143		nC

performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: pulse width $\leq 300 \ \mu$ s, duty cycle $\leq 2\%$. 4. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



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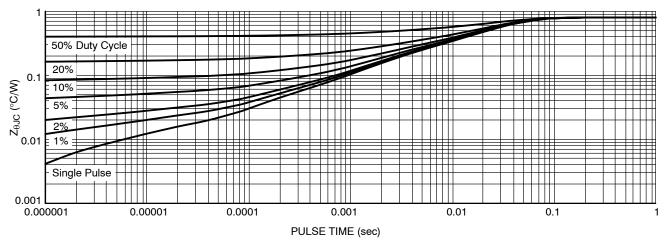


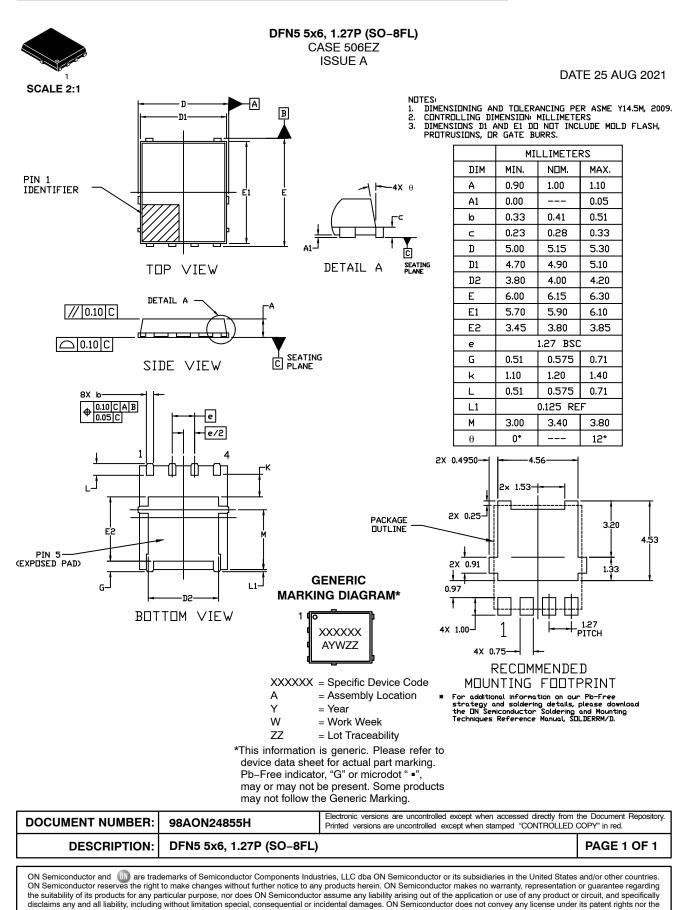
Figure 13. Thermal Impedance

DEVICE ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
NTMFS0D7N03CGT1G	0D7NG	DFN5 (Pb–Free)	1500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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